FAIRCHILD SEMICONDUCTOR™

August 1984
Revised May 1999

MM74HC4051 • MM74HC4052 • MM74HC4053 8-Channel Analog Multiplexer • Dual 4-Channel Analog Multiplexer • Triple 2-Channel Analog Multiplexer

General Description

The MM74HC4051, MM74HC4052 and MM74HC4053 multiplexers are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "on" resistance and low "off" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Also these switches contain linearization circuitry which lowers the on resistance and increases switch linearity. These devices allow control of up to ±6V (peak) analog signals with digital control signals of 0 to 6V. Three supply pins are provided for V_{CC}, ground, and V_{EE}. This enables the connection of 0–5V logic signals when V_{CC} = 5V and an analog input range of ±5V when V_{EE} = 5V. All three devices also have an inhibit control which when HIGH will disable all switches to their off state. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to V_{CC} and ground.

MM74HC4051: This device connects together the outputs of 8 switches, thus achieving an 8 channel Multiplexer. The binary code placed on the A, B, and C select lines determines which one of the eight switches is "on", and connects one of the eight inputs to the common output.

MM74HC4052: This device connects together the outputs of 4 switches in two sets, thus achieving a pair of 4-channel multiplexers. The binary code placed on the A, and B select lines determine which switch in each 4 channel section is "on", connecting one of the four inputs in each section to its common output. This enables the implementation of a 4-channel differential multiplexer.

MM74HC4053: This device contains 6 switches whose outputs are connected together in pairs, thus implementing a triple 2 channel multiplexer, or the equivalent of 3 single-pole-double throw configurations. Each of the A, B, or C select lines independently controls one pair of switches, selecting one of the two switches to be "on".

Features

- Wide analog input voltage range: ±6V
- Low "on" resistance:
  50 typ. (V_{CC}–V_{EE} = 4.5V)
  30 typ. (V_{CC}–V_{EE} = 9V)
- Logic level translation to enable 5V logic with ±5V analog signals
- Low quiescent current: 80 μA maximum (74HC)
- Matched Switch characteristic

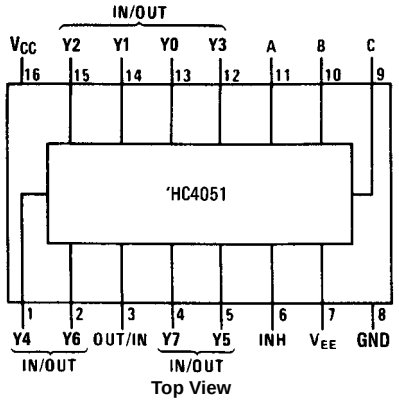
Ordering Code:

Order Number	Package Number	Package Description
MM74HC4051M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4051WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4051SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4051MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4051N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-0010.300" Wide
MM74HC4052M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4052WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4052SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4052MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4052N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-0010.300" Wide
MM74HC4053M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4053WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4053SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4053MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4053N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-0010.300" Wide

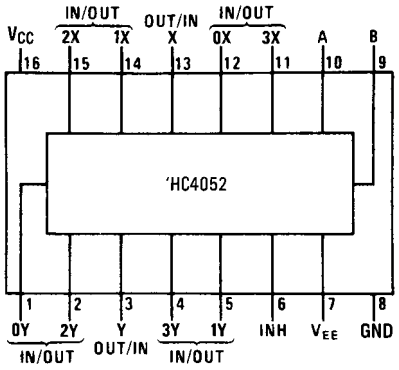
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

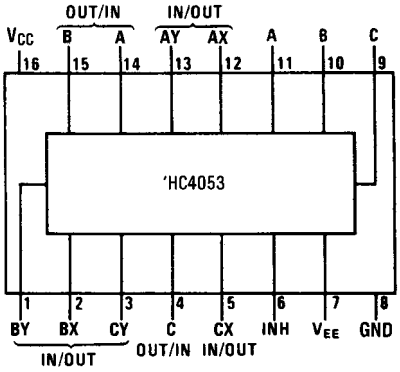
Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View



Top View



Top View

Truth Tables

MM744051

Input				"ON"
Inh	C	B	A	Channel
H	X	X	X	None
L	L	L	L	Y0
L	L	L	H	Y1
L	L	H	L	Y2
L	L	H	H	Y3
L	H	L	L	Y4
L	H	L	H	Y5
L	H	H	L	Y6
L	H	H	H	Y7

MM744052

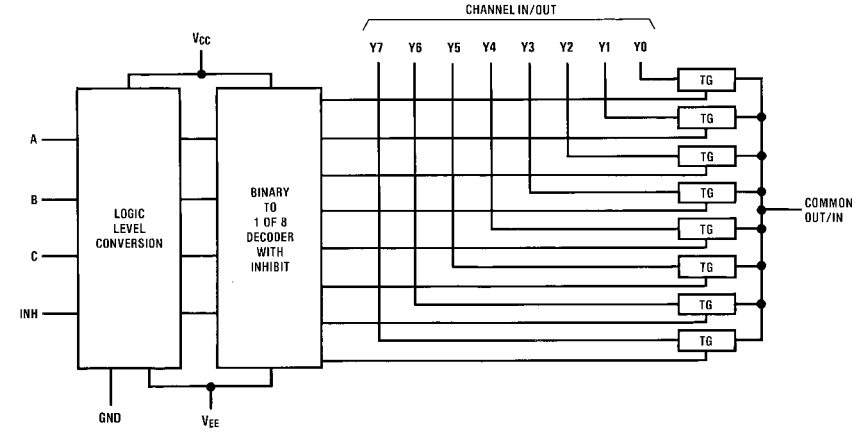
Inputs			"ON" Channels	
Inh	B	A	X	Y
H	X	X	None	None
L	L	L	0X	0Y
L	L	H	1X	1Y
L	H	L	2X	2Y
L	H	H	3X	3Y

MM744053

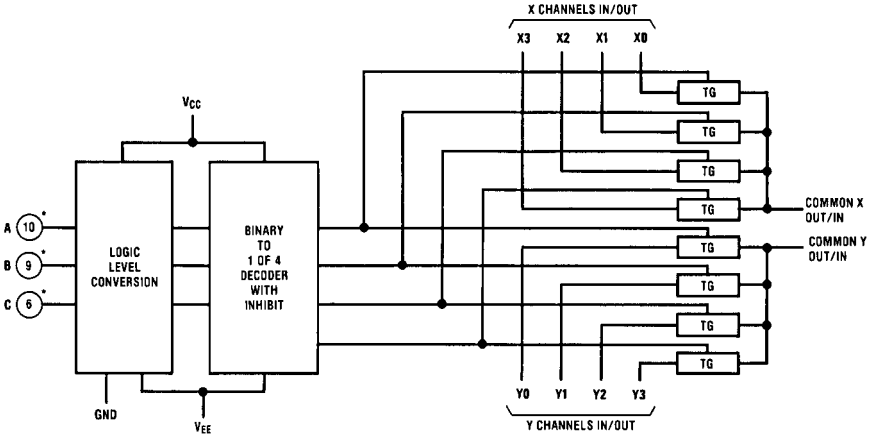
Input				"ON" Channels		
Inh	C	B	A	C	b	a
H	X	X	X	None	None	None
L	L	L	L	CX	BX	AX
L	L	L	H	CX	BX	AY
L	L	H	L	CX	BY	AX
L	L	H	H	CX	BY	AY
L	H	L	L	CY	BX	AX
L	H	L	H	CY	BX	AY
L	H	H	L	CY	BY	AX
L	H	H	H	CY	BY	AY

Logic Diagrams

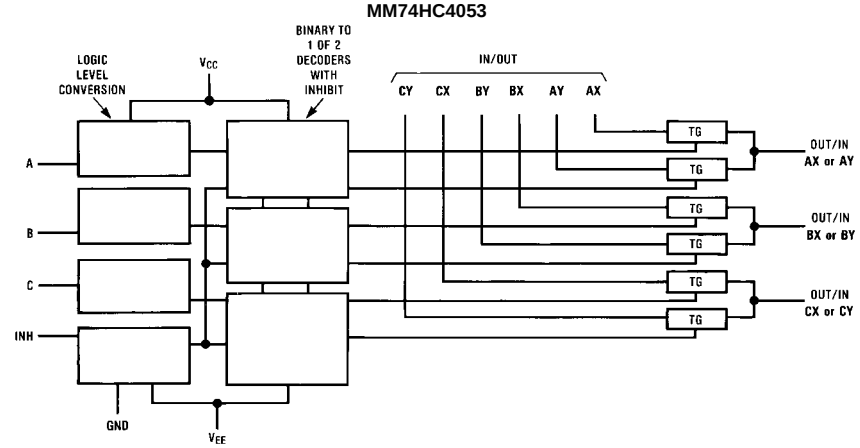
MM74HC4051



MM74HC4052



MM74HC4053



Absolute Maximum Ratings (Note 1)

(Note 2)

Supply Voltage (V_{CC})	−0.5 to +7.5V
Supply Voltage (V_{EE})	+0.5 to −7.5V
Control Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
Switch I/O Voltage (V_{IO})	V_{EE} −0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
Output Current, per pin (I_{OUT})	±25 mA
V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T_L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
Supply Voltage (V_{EE})	0	−6	V
DC Input or Output Voltage			
(V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	−40	+85	°C
Input Rise or Fall Times			
(t_r, t_f) V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter		Conditions	V_{EE}	V_{CC}	T_A = 25°C	T_A = −40 to 85°C	T_A = −55 to 125°C	Units
						Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level				2.0V		1.5	1.5	1.5	V
	Input Voltage				4.5V		3.15	3.15	3.15	V
					6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum LOW Level				2.0V		0.5	0.5	0.5	V
	Input Voltage				4.5V		1.35	1.35	1.35	V
					6.0V		1.8	1.8	1.8	V
R_{ON}	Maximum "ON" Resistance		V_{INH} = V_{IL}, I_S = 2.0 mA	GND	4.5V	40	160	200	240	Ω
	(Note 5)		V_{IS} = V_{CC} to V_{EE}	−4.5V	4.5V	30	120	150	170	Ω
			(Figure 1)	−6.0V	6.0V	20	100	125	140	Ω
			V_{INH} = V_{IL}, I_S = 2.0 mA	GND	2.0V	100	230	280	320	Ω
			V_{IS} = V_{CC} or V_{EE}	GND	4.5V	40	110	140	170	Ω
			(Figure 1)	−4.5V	4.5V	20	90	120	140	Ω
				−6.0V	6.0V	15	80	100	115	Ω
R_{ON}	Maximum "ON" Resistance		V_{CTL} = V_{IL}	GND	4.5V	10	20	25	25	Ω
	Matching		V_{IS} = V_{CC} to GND	−4.5V	4.5V	5	10	15	15	Ω
				−6.0V	6.0V	5	10	12	15	Ω
I_{IN}	Maximum Control		V_{IN} = V_{CC}or GND				±0.1	±1.0	±1.0	µA
	Input Current		V_{CC} = 2–6V							
I_{CC}	Maximum Quiescent		V_{IN} = V_{CC} or GND	GND	6.0V		8	80	160	µA
	Supply Current		I_{OUT} = 0 µA	−6.0V	6.0V		16	160	320	µA
I_{IZ}	Maximum Switch "OFF"		V_{OS} = V_{CC}or V_{EE}	GND	6.0V		±60	±600	±600	nA
	Leakage Current		V_{IS} = V_{EE}or V_{CC}	−6.0V	6.0V		±100	±1000	±1000	nA
	(Switch Input)		V_{INH} = V_{IH} (Figure 2)							
I_{IZ}	Maximum Switch		V_{IS} = V_{CC} to V_{EE}	GND	6.0V		±0.2	±2.0	±2.0	µA
	"ON" Leakage	HC4051	V_{INH} = V_{IL}	−6.0V	6.0V		±0.4	±4.0	±4.0	µA
	Current		(Figure 3)							
			V_{IS} = V_{CC} to V_{EE}	GND	6.0V		±0.1	±1.0	±1.0	µA
		HC4052	V_{INH} = V_{IL} (Figure 3)	−6.0V	6.0V		±0.2	±2.0	±2.0	µA
			V_{IS} = V_{CC} to V_{EE}	GND	6.0V		±0.1	±1.0	±1.0	µA
		HC4053	V_{INH} = V_{IL} (Figure 3)	−6.0V	6.0V		±0.1	±1.0	±1.0	µA

DC Electrical Characteristics (Continued)

Symbol	Parameter		Conditions	V_{EE}	V_{CC}	$T_A = 25°C$	$T_A = -40$ to $85°C$	$T_A = -55$ to $125°C$	Units
						Typ	Guaranteed Limits		
I_{IZ}	Maximum Switch		$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±0.2	±2.0	±2.0	µA
	"OFF" Leakage	HC4051	$V_{IS} = V_{EE}$ or V_{CC}	−6.0V	6.0V		±0.4	±4.0	±4.0	µA
	Current (Common Pin)		$V_{INH} = V_{IH}$							
			$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±0.1	±1.0	±1.0	µA
		HC4052	$V_{IS} = V_{EE}$ or V_{CC}	−6.0V	6.0V		±0.2	±2.0	±2.0	µA
			$V_{INH} = V_{IH}$							
			$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±0.1	±1.0	±1.0	µA
		HC4053	$V_{IS} = V_{EE}$ or V_{CC}	−6.0V	6.0V		±0.1	±1.0	±1.0	µA
			$V_{INH} = V_{IH}$							

Note 4: For a power supply of 5V ±10% the worst case on resistances (R_{ON}) occurs for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occur for CMOS at the higher voltage and so the 5.5V values should be used.

Note 5: At supply voltages (V_{CC}–V_{EE}) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

AC Electrical Characteristics

V_{CC} = 2.0V–6.0V, V_{EE} = 0V–6V, C_L = 50 pF (unless otherwise specified)

Symbol	Parameter	Conditions		V_{EE}	V_{CC}	$T_A = 25°C$	$T_A = -40$ to $85°C$	$T_A = -55$ to $125°C$	Units
						Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation			GND	2.0V	25	60	75	90	ns
	Delay Switch In to Out			GND	4.5V	5	12	15	18	ns
				−4.5V	4.5V	4	8	12	14	ns
				−6.0V	6.0V	3	7	11	13	ns
t_{PZL}, t_{PZH}	Maximum Switch Turn	R_L = 1 kΩ		GND	2.0V	92	355	435	515	ns
	"ON" Delay			GND	4.5V		69	87	103	ns
				−4.5V	4.5V	16	46	58	69	ns
				−6.0V	6.0V	15	41	51	62	ns
t_{PHZ}, t_{PLZ}	Maximum Switch Turn			GND	2.0V	65	290	365	435	ns
	"OFF" Delay			GND	4.5V	28	58	73	87	ns
				−4.5V	4.5V	18	37	46	56	ns
				−6.0V	6.0V	16	32	41	48	ns
f_{MAX}	Minimum Switch			GND	4.5V	30				MHz
	Frequency Response			−4.5V	4.5V	35				MHz
	20 log (V_I/V_O) = 3 dB									
	Control to Switch	R_L = 600Ω,	V_{IS} = 4 V_{PP}	0V	4.5V	1080				mV
	Feedthrough Noise	f = 1 MHz,	V_{IS} = 8 V_{PP}	−4.5V	4.5V	250				mV
		C_L = 50 pF								
	Crosstalk between	R_L = 600Ω,	V_{IS} = 4 V_{PP}	0V	4.5	−52				dB
	any Two Switches	f = 1 MHz	V_{IS} = 8 V_{PP}	−4.5V	4.5V	−50				dB
	Switch OFF Signal	R_L = 600Ω,	V_{IS} = 4 V_{PP}	0V	4.5V	−42				dB
	Feedthrough	f = 1 MHz,	V_{IS} = 8 V_{PP}	−4.5V	4.5V	−44				dB
	Isolation	$V_{CTL} = V_{IL}$								
THD	Sinewave Harmonic	R_L = 10 kΩ,	V_{IS} = 4 V_{PP}	0V	4.5V	0.013				%
	Distortion	C_L = 50 pF,	V_{IS} = 8 V_{PP}	−4.5V	4.5V	0.008				%
		f = 1 kHz								
C_{IN}	Maximum Control					5	10	10	10	pF
	Input Capacitance									
C_{IN}	Maximum Switch	Input				15				pF
	Input Capacitance	4051 Common				90				
		4052 Common				45				
		4053 Common				30				
C_{IN}	Maximum Feedthrough Capacitance					5				pF

AC Test Circuits and Switching Time Waveforms

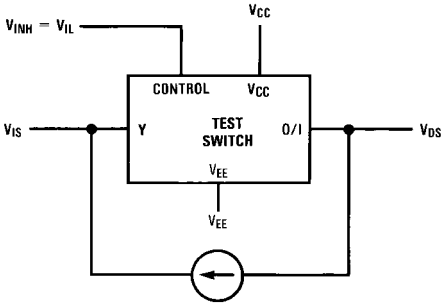


FIGURE 1. "ON" Resistance

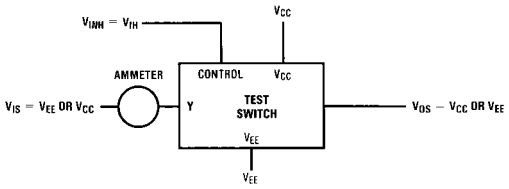


FIGURE 2. "OFF" Channel Leakage Current

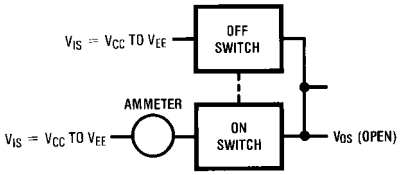


FIGURE 3. "ON" Channel Leakage Current

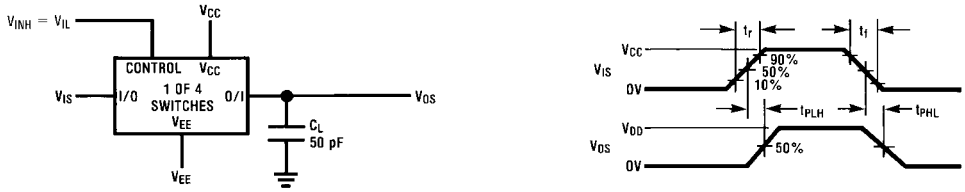


FIGURE 4. t_{PHL}, t_{PLH} Propagation Delay Time Signal Input to Signal Output

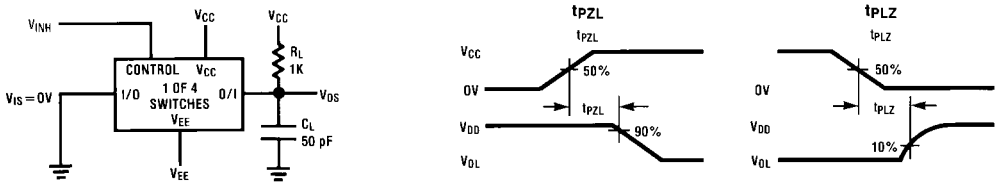


FIGURE 5. t_{PZL}, t_{PLZ} Propagation Delay Time Control to Signal Output

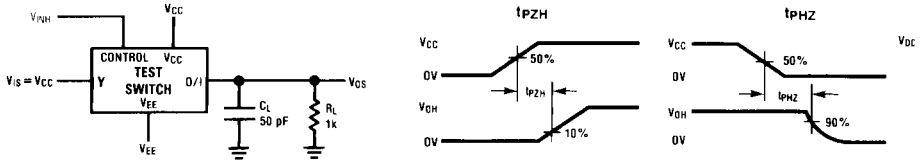


FIGURE 6. t_{PZH}, t_{PHZ} Propagation Delay Time Control to Signal Output

AC Test Circuits and Switching Time Waveforms (Continued)

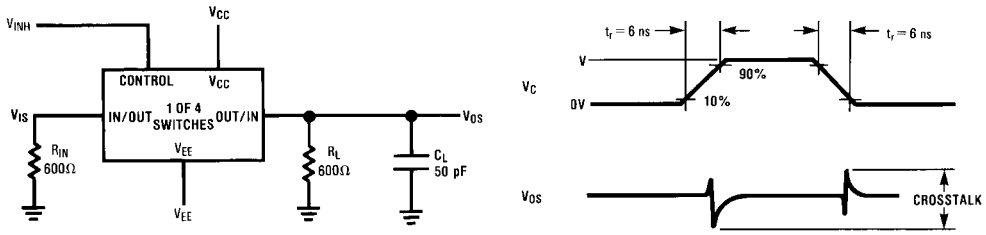


FIGURE 7. Crosstalk: Control Input to Signal Output

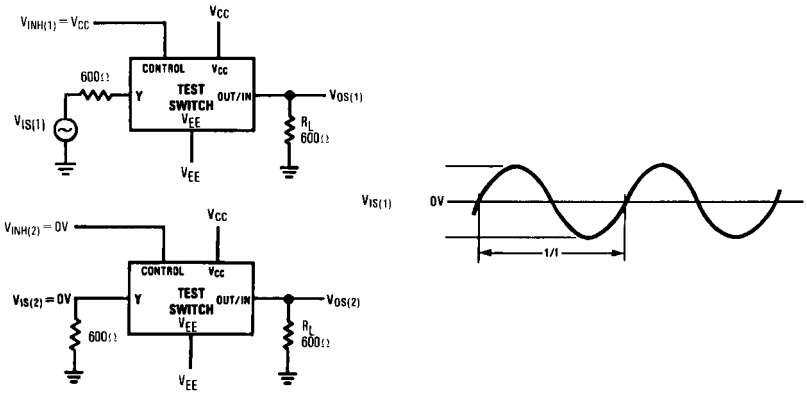
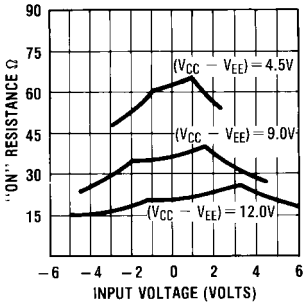


FIGURE 8. Crosstalk Between Any Two Switches

Typical Performance Characteristics

Typical "On" Resistance vs Input Voltage

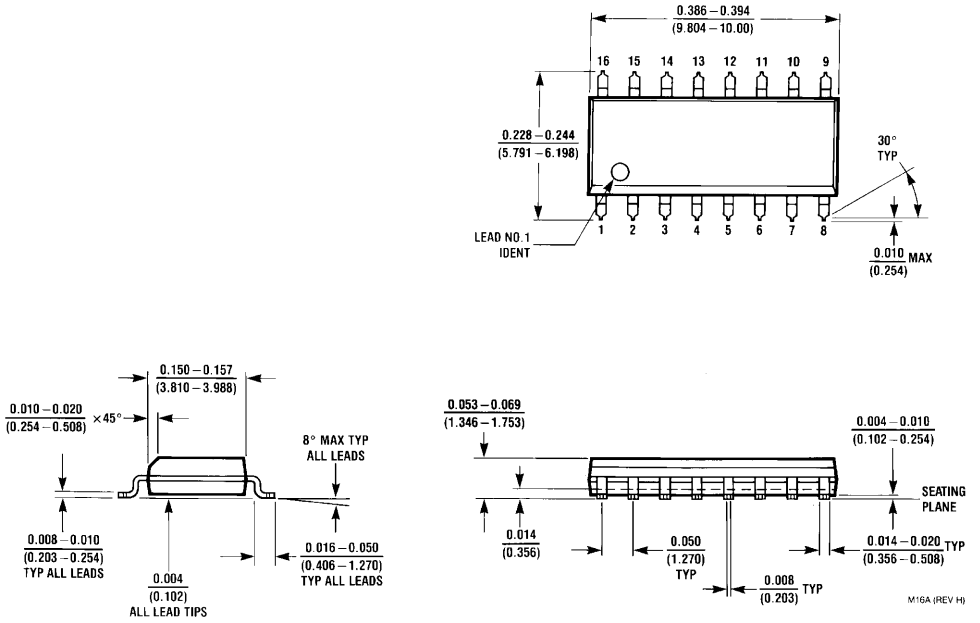


V_{CC}=−V_{EE}

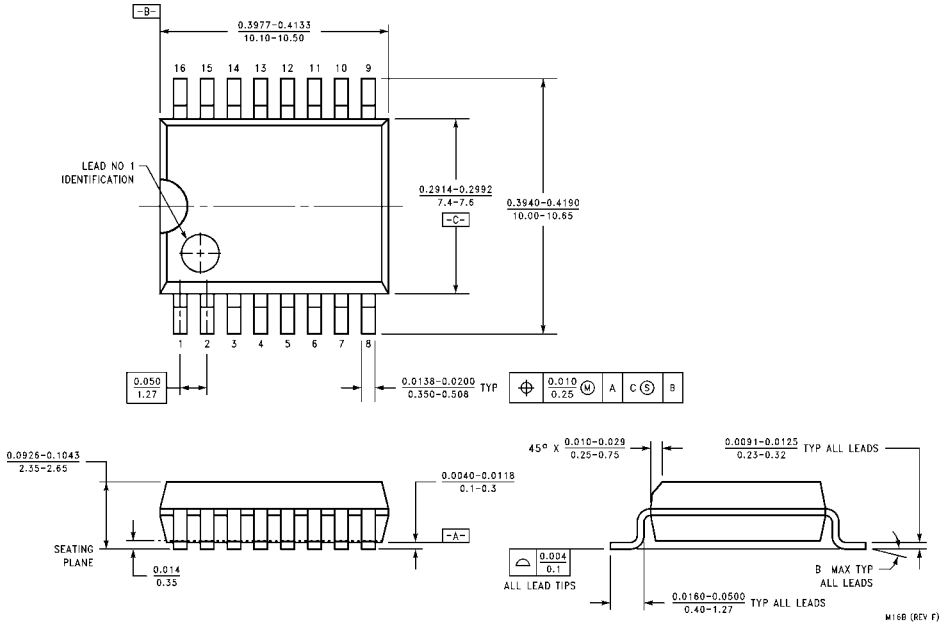
Special Considerations

In certain applications the external load-resistor current may include both V_{CC} and signal line components. To avoid drawing V_{CC} current when switch current flows into the analog switch pins, the voltage drop across the switch must not exceed 1.2V (calculated from the ON resistance).

Physical Dimensions inches (millimeters) unless otherwise noted

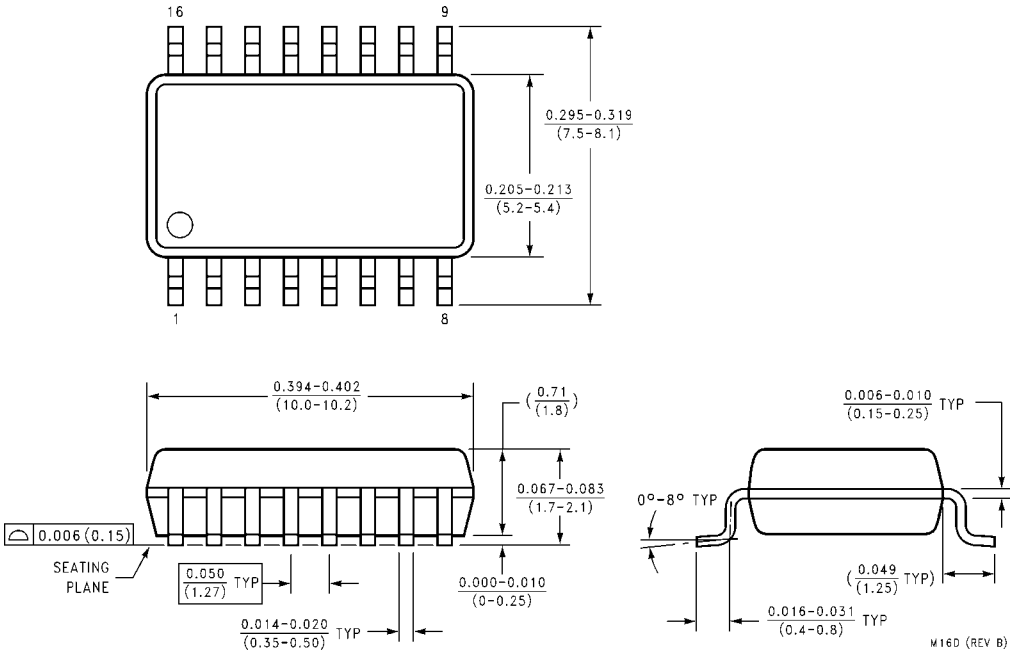


16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M16A



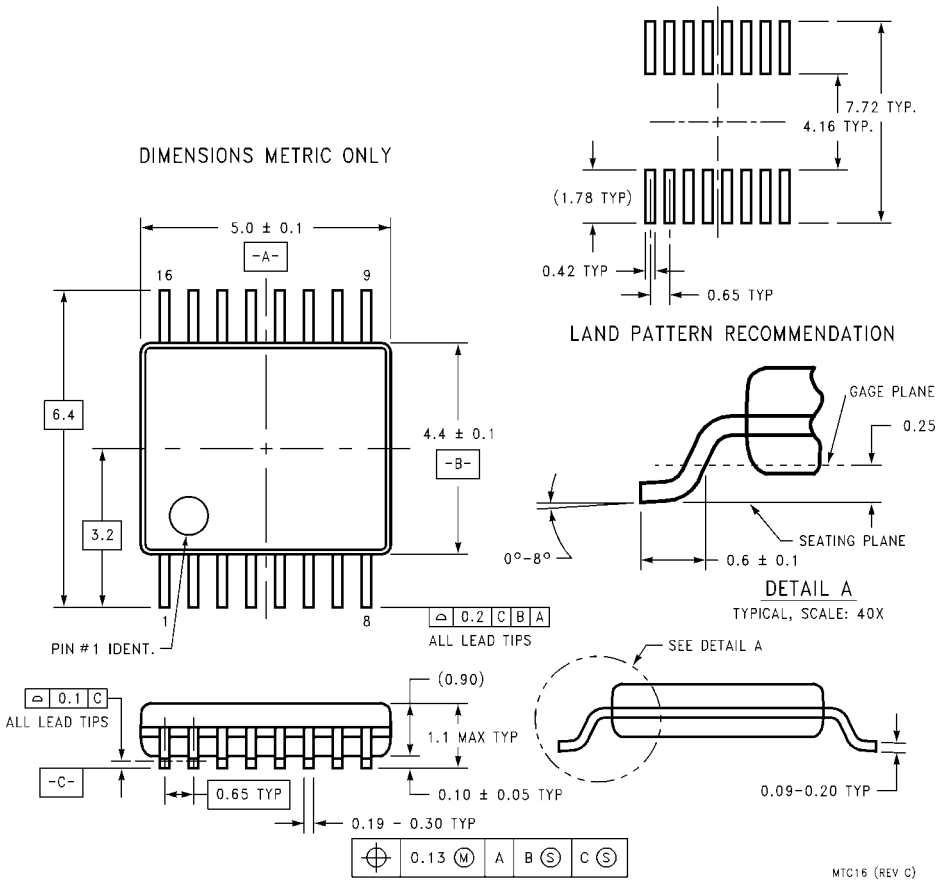
16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M16B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



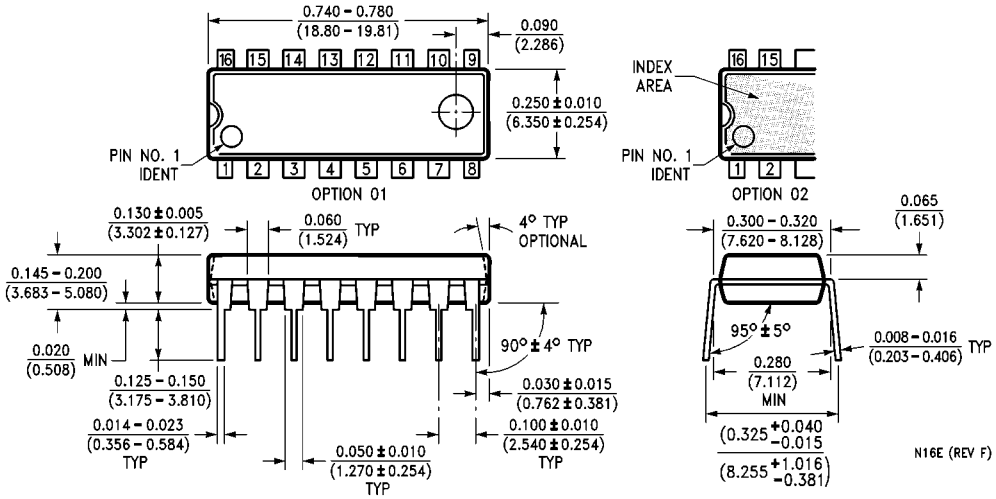
16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M16D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC16

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Package Number N16E

LIFE SUPPORT POLICY

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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